

220158US-2X DIV

#2 / PRE-AMDT  
A  
C. Quer  
4/19/02

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
MASATAKA HASEGAWA ET AL : ATTN: APPLICATION DIVISION  
SERIAL NO: NEW U.S. APPLICATION :  
FILED: HEREWITH :  
FOR: DIAMOND SEMICONDUCTOR AND  
METHOD FOR THE FABRICATION  
THEREOF

PRELIMINARY AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS  
WASHINGTON, D.C. 20231

SIR:

Prior to a first examination on the merits, please amend the above-identified application as follows:

IN THE CLAIMS

✓  
Please cancel claims 1 and 2 without prejudice.

REMARKS

Favorable consideration of this application, as presently amended, is respectfully requested.

The present application is a divisional of copending parent U.S. application serial no. 09/621,360. In that parent application Claims 3-6 were withdrawn as directed to a non-